Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:

Metal

Overall Length:

0.505 inches

Overall Height:

0.505 inches

Mounting Facility Quantity:

1

Mounting Method:

Threaded stud

Overall Width Across Flats:

0.562 inches

Thread Size:

0.250 inches

Semiconductor Material:

Silicon

Voltage Rating In Volts Per Characteristic:

500.0 breakover voltage, dc

Current Rating Per Characteristic:

225.00 amperes average forward current averaged over a full 60-hz cycle

Power Rating Per Characteristic:

500.0 milliwatts small-signal input power, common-collector blank

Maximum Operating Tempurature Per Measurement Point:

150.0 degrees celsius junction

Thread Series Designator:

Unf

Terminal Type And Quantity:

2 tab, solder lug and 2 threaded stud

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

No

Fiig:

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